GS5581/B

1.5MHz, 1A Synchronous Step-Down Converter

Product Description

The GS5581/B are high-efficiency, high frequency synchronous step-down DC-DC regulator ICs capable of delivering up to 1A output currents. The GS5581/B can operate over a wide input voltage range from 2.6V to 6V and integrates main switch and synchronous switch with very low $R_{DS(ON)}$ to minimize the conduction loss.

It is ideal for powering portable equipment that runs from a single cell Lithium-Ion (Li+) battery. The output voltage can be regulated as low as 0.6V.

The GS5581/B offers two operation modes, PWM mode and PFM Mode switching control, which allows a high efficiency over the wider range of the load.

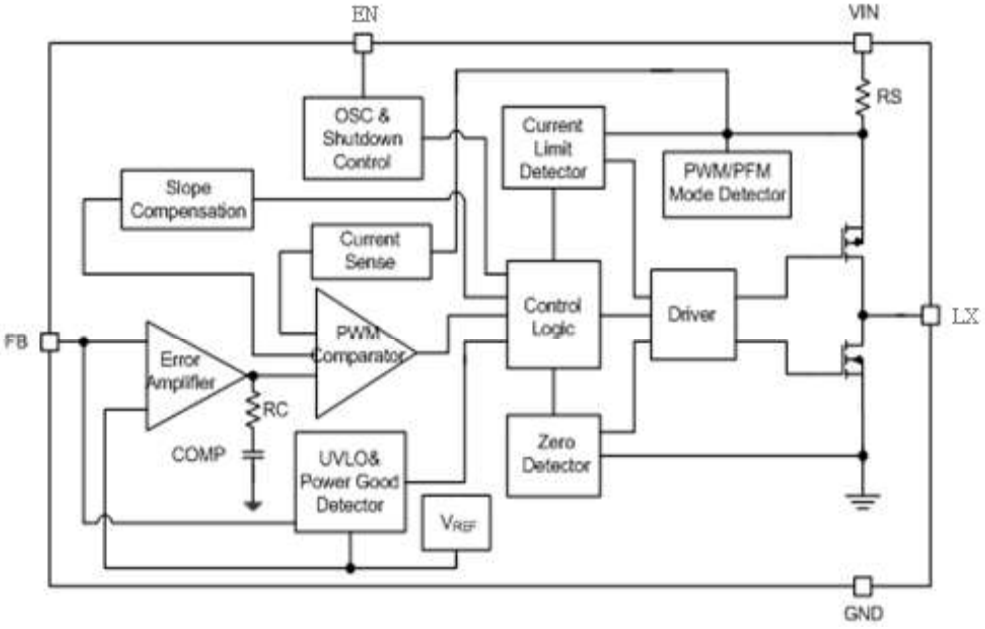
Features

- High Efficiency: Up to 96%
- 1.5MHz Constant Frequency Operation
- 1A Output Current
- No Schottky Diode Required
- 2.6V to 6V Input Voltage Range
- Adjustable Output Voltage Range Options from 0.6V to V_{IN}
- Slope Compensated Current Mode Control for Excellent Line and Load Transient Response
- Short Circuit Protection
- Thermal Fault Protection
- Inrush Current Limit and Soft Start
- <1μA Shutdown Current
- Tiny DFN2x2-6L and SOT23-5L Packages
- RoHS Compliant, 100%Pb & Halogen Free

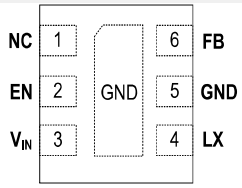
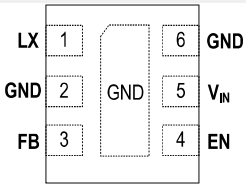
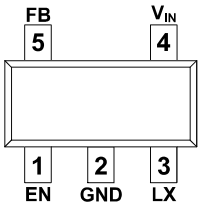
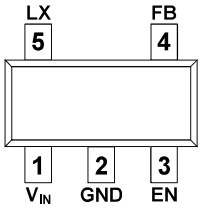
Applications

- Cellular and Smart Phones
- Wireless and DSL Modems
- PDAs
- Digital Still and Video Cameras
- MP3 Players

Block Diagram

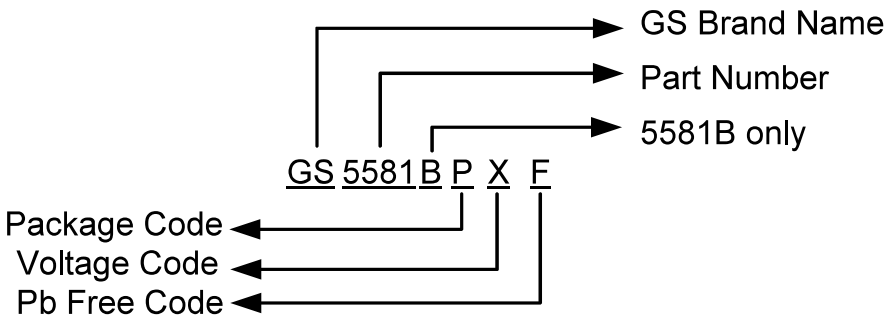


Packages & Pin Assignments

GS5581FAF(DFN2x2-6L)	GS5581BFAF(DFN2x2-6L)
 (Top View)	 (Top View)
GS5581LAF(SOT23-5L)	**GS5581LBF(SOT23-5L)**
 (Top View)	 (Top View)

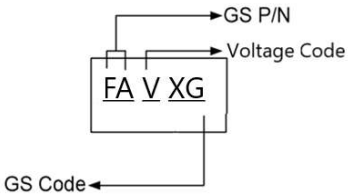
Pin Name	Description
EN	Chip Enable Pin. Drive EN above 1.5V to turn on the part. Drive EN below 0.4V to turn it off. Do not leave EN floating.
GND	Analog ground pin.
LX	Power Switch Output. It is the switch node connection to Inductor. This pin connects to the drains of the internal P-ch and N-ch MOSFET switches.
V_{IN}	Analog supply input pin.
NC	No connected.
FB	Output Voltage Feedback Pin. An internal resistive divider divides the output voltage down for comparison to the internal reference voltage.

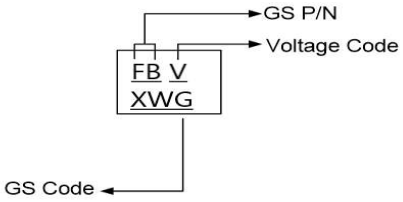
Ordering Information

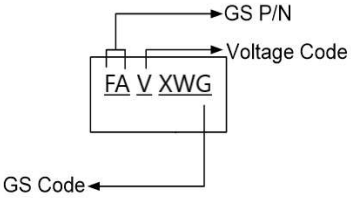


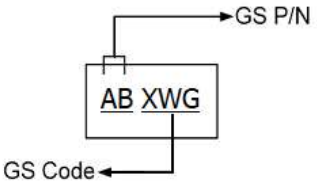
Part Number	Temperature Range	Output Voltage	Package
GS5581FAF	-40ºC to 85ºC	ADJ	DFN2x2-6L
GS5581BFAF	-40ºC to 85ºC	ADJ	DFN2x2-6L
GS5581LAF	-40ºC to 85ºC	ADJ	SOT23-5L
GS5581LBF	-40ºC to 85ºC	ADJ	SOT23-5L

Marking Information









Part Number	Package	GS P/N	Voltage Code	GS Code
GS5581FAF	DFN2x2-6L	FA	A	XG
GS5581BFAF	DFN2x2-6L	FB	A	XWG
GS5581LAF	SOT23-5L	FA	A	XWG
		AB	-	XWG
GS5581LBF	SOT23-5L	FA	B	XWG

Absolute Maximum Ratings (Note 1)

Symbol	Description	Value		Units
V_{IN}	Supply Voltage	-0.3 to 6.5		V
	RUN,FB Voltages	-0.3 to 6.5		V
V_{SW}	SW Voltage	-0.3 to (V_{IN}+0.3)		V
I_{PK}	Peak SW sink and Source Current	2.5		A
T_A	Operating Temperature Range	-40 to +85		°C
T_J	Junction Temperature **(Note 2)**	125		°C
T_{STG}	Storage Temperature Range	-65 to +150		°C
T_{LEAD}	Lead Temperature(Soldering,10s)	300		°C
ESD	HBM(Human Body Mode)	2000		V
	MM(Machine Mode)	200		
θ_{JA}	Thermal Resistance Junction to Ambient	DFN2x2-6L	130	°C/W
		SOT-23-5L	250	

Typical Application Circuit

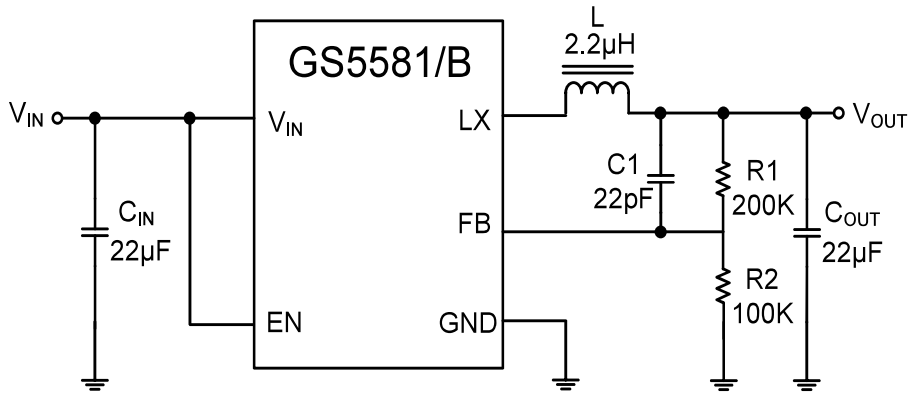


Figure1. GS5581/B Adjustable Output Voltage Regulator

Electrical Characteristics (Note 3)

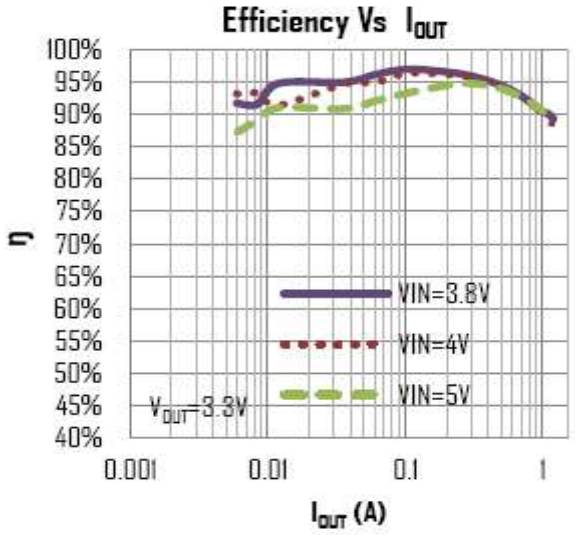
V_{IN}=V_{EN}=3.6V, V_{OUT}=1.8V, T_A=25°C, unless otherwise noted.

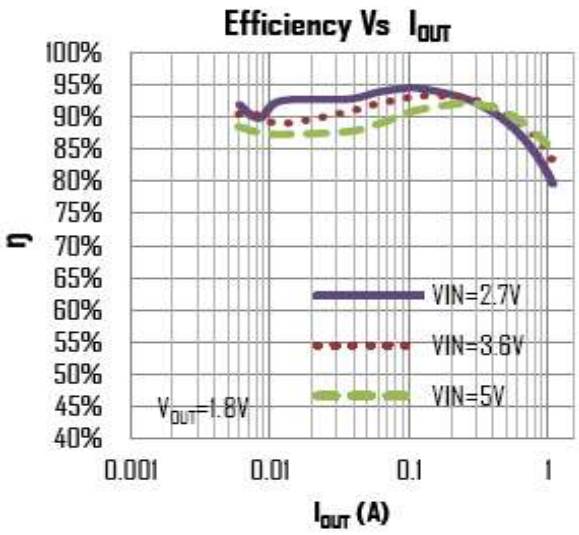
Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_{IN}	Input Voltage	-	2.6	-	6	V
V_{UVLO}	UVLO Threshold	V_{IN} Rising	-	2.31	2.45	V
I_Q	Input DC Supply Current	I_{LOAD}=0mA	-	40	70	µA
I_{SHDN}	Shutdown Mode	V_{EN}=0V, V_{IN}=4.2V **(Note 4)**	-	-	1.0	
V_{FB}	Regulated Feedback Voltage	T_A=25°C	0.588	0.600	0.612	V
		0°C≤T_A≤85°C	0.586	0.600	0.613	
		-40°C≤T_A≤85°C	0.585	0.600	0.615	
V_{EN}	V_{EN} Threshold	-	0.4	1.0	1.5	V
I_{EN}	I_{EN} Leakage Current	-	-	-	±1.0	µA
I_{SW}	SW Leakage Current	V_{EN}=0V,V_{IN}=V_{LX}=5V	-	-	±10	µA
$R_{DS(ON)H}$	On Resistance of PMOS	I_{SW}=100mA	-	0.28	-	Ω
$R_{DS(ON)L}$	ON Resistance of NMOS		-	0.2	-	
I_{PK}	Peak Current Limit	V_{IN}=3V,V_{OUT}=90%	1.5	-	-	A
REG_{LINE}	Output Voltage Line Regulation	V_{IN}=2.7V to 5.5V	-	0.2	-	%
REG_{LOAD}	Output Voltage Load Regulation	VOUT=1.8V, Iout From 0.2A to 0.4A	-	0.1	-	
F_{OSC}	Oscillation Frequency		-	1.5	-	MHz

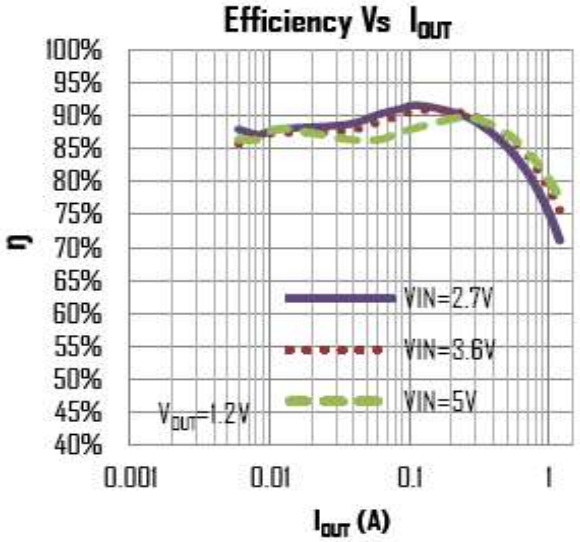
Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.
Note 2: T_J is calculated from the ambient temperature T_A and power dissipation P_D according to the following formula: $T_J = T_A + (P_D) \times (\theta_{JA})$.
Note 3: 100% production test at +25°C. Specifications over the temperature range are guaranteed by design and characterization.
Note 4: Dynamic supply current is higher due to the gate charge being delivered at the switching frequency.

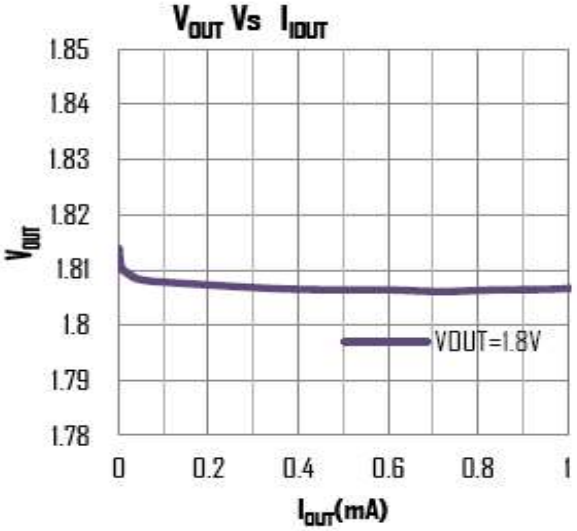
Typical Performance Characteristics

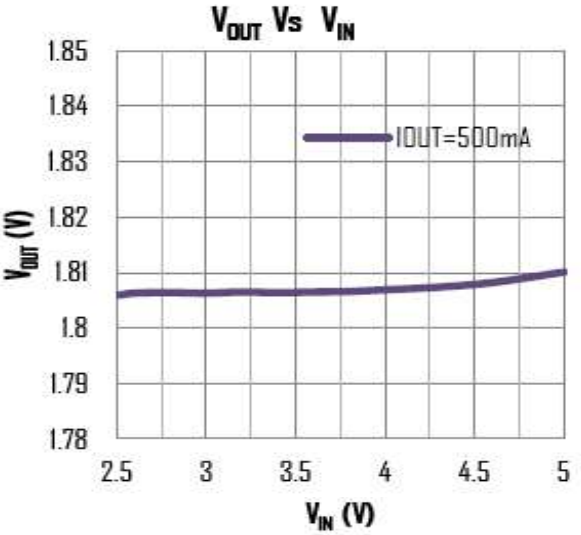
T_A=25ºC, unless Otherwise noted







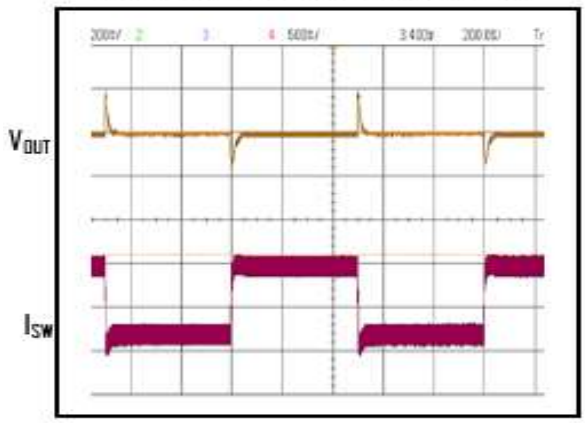




Typical Performance Characteristics (Continue)

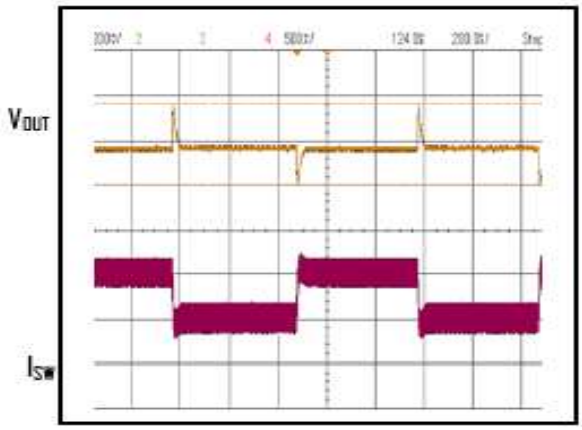
T_A=25ºC, unless Otherwise noted

Load Transient Response
V_{IN}=3.6V, V_{OUT}=1.2V,I_{OUT}= 0.2A to 1A



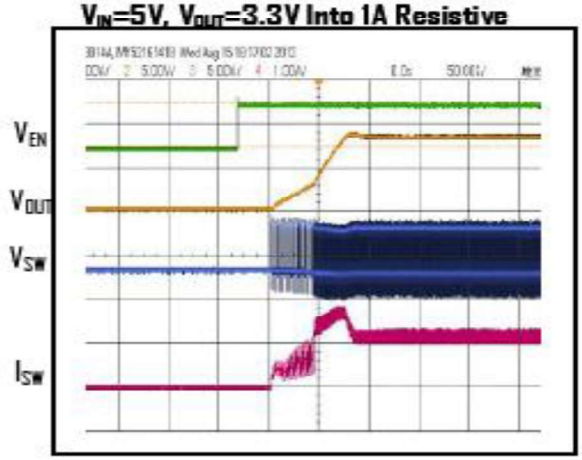
2ms/div

Load Transient Response
V_{IN}=5V, V_{OUT}=3.3V,I_{OUT}= 0.5A to 1A



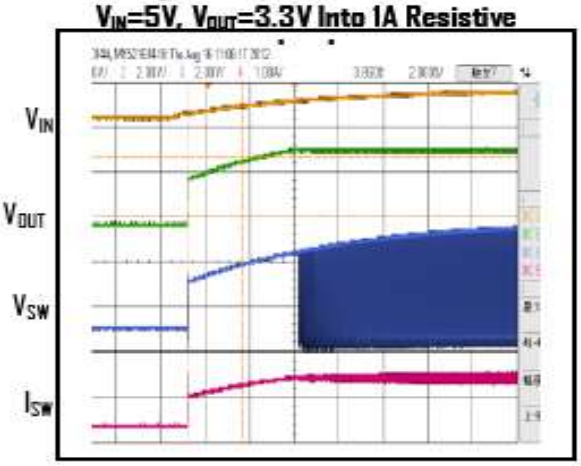
2ms/div

Startup Waveform with EN Turn on
V_{IN}=5V, V_{OUT}=3.3V Into 1A Resistive



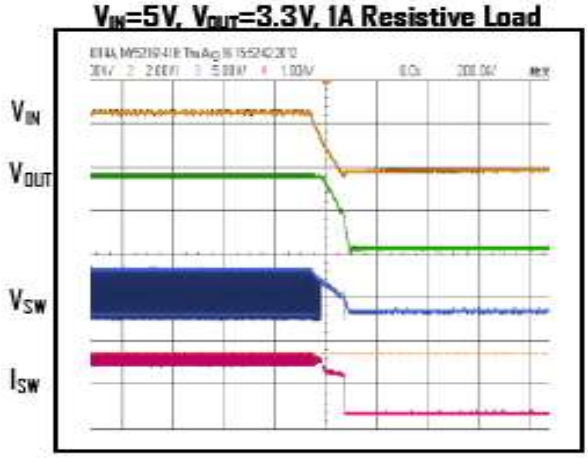
50µs/div

Startup Waveform with EN Tied to IN
V_{IN}=5V, V_{OUT}=3.3V Into 1A Resistive



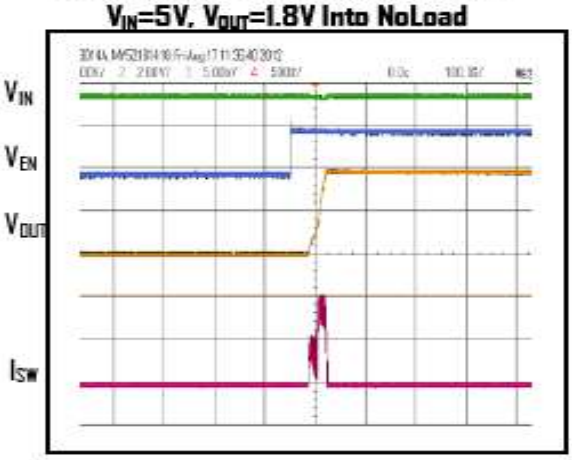
2ms/div

Shutdown Waveform with EN Tied to IN
V_{IN}=5V, V_{OUT}=3.3V, 1A Resistive Load



200µs/div

Startup Waveform with EN Tied to IN
V_{IN}=5V, V_{OUT}=1.8V Into NoLoad



100µs/div

Functional Description

GS5581/B is a synchronous buck regulator IC that integrates the PWM/PFM control, high-side and low-side MOSFETs on the same die to minimize the switching transition loss and conduction loss. With ultra low $R_{DS(ON)}$ power switches and proprietary PWM control, this regulator IC can achieve the highest efficiency and the highest switch frequency simultaneously to minimize the external inductor and capacitor size, and thus achieving the minimum solution footprint.

The GS5581/B requires only three external power components (C_{IN}, C_{OUT} and L). The adjustable version can be programmed with external feedback to any voltage, ranging from 0.6V to the input voltage.

The internal error amplifier and compensation provides excellent transient response, load, and line regulation. Soft start function prevents input inrush current and output overshoot during start up.

Applications Information

Setting the Output Voltage

The internal reference V_{REF} is 0.6V(Typical).The output voltage is divided by a resistor,R1 and R2 to the FB pin. The output voltage is given by:

$$V_{OUT} = V_{REF} \times (1 + \frac{R_1}{R_2})$$

Inductor Selection

For most designs, the GS5581/B operates with inductors of 1μH to 4.7μH. Low inductance values are physically smaller but require faster switching, which results in some efficiency loss. The inductor value can be derived from the following equation:

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times \Delta I_L \times f_{OSC}}$$

Where ΔI_L is inductor Ripple Current. Large value inductors result in lower ripple current and small value inductors result in high ripple current. For optimum voltage-positioning load transients, choose an inductor with DC series resistance in the 50mΩ to 150mΩ range.

Input Capacitor Selection

With the maximum load current at 1.0A, the maximum ripple current through input capacitor is about 0.6Arms. A typical X7R or better grade ceramic capacitor with 6V rating and greater than 10uF capacitance can handle this ripple current well. To minimize the potential noise problem, place this ceramic capacitor really close to the IN and GND pins. Care should be taken to minimize the loop area formed by C_{IN}, and IN/GND pins.

Output Capacitor Selection

The output capacitor is required to keep the output voltage ripple small and to ensure regulation loop stability. The output capacitor must have low impedance at the switching frequency. Ceramic capacitors with X5R or X7R dielectrics are recommended due to their low ESR and high ripple current ratings.

The output ripple ΔV_{OUT} is determined by:

$$\Delta V_{OUT} \leq \frac{V_{OUT} x (V_{IN} - V_{OUT})}{V_{IN} x f_{OSC} x L} x \left(ESR + \frac{1}{8 x f_{OSC} x C3} \right)$$

A 10μF ceramic Capacitor can satisfy most applications.

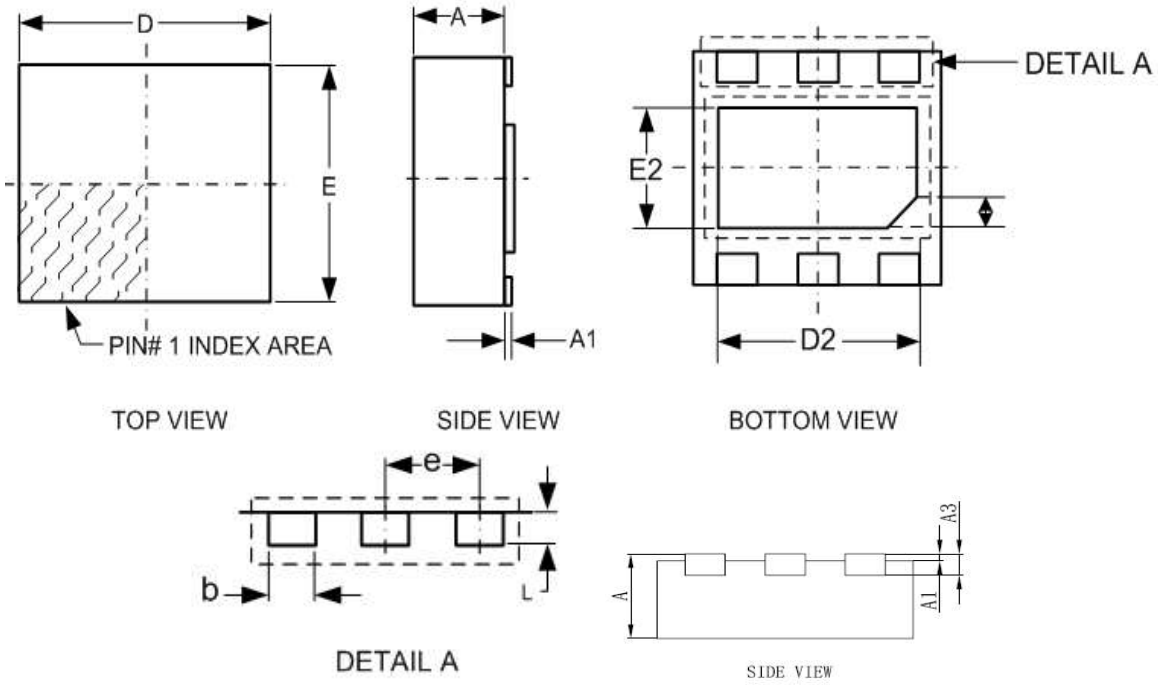
PC Board Layout Checklist

When laying out the printed circuit board, the following checking should be used to ensure proper operation of the GS5581/B. Check the following in your layout:

1. The power traces, consisting of the GND trace, the SW trace and the V_{IN} trace should be kept short, direct and wide.
2. Does the (+) plates of C_{IN} connect to V_{IN} as closely as possible. This capacitor provides the AC current to the internal power MOSFET.
3. Keep the switching node, SW, away from the sensitive V_{OUT} node.
4. Keep the (-) plates of C_{IN} and C_{OUT} as close as possible.

Package Dimension

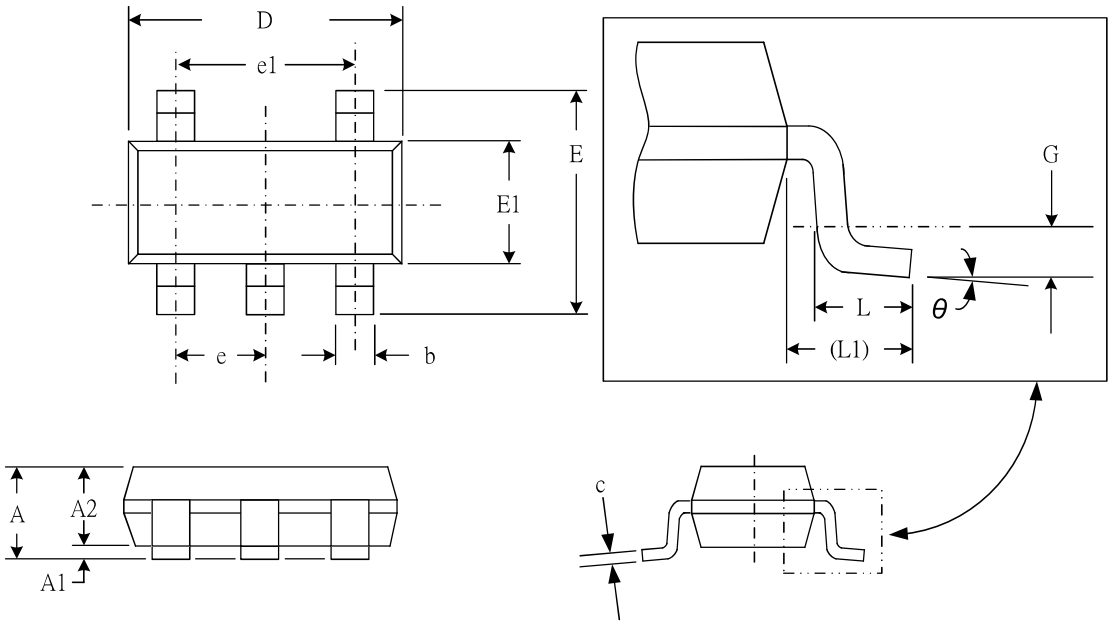
DFN2x2-6L(0.75-0.65)



Dimensions						
SYMBOL	Millimeters			Inches		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.70	0.75	0.80	0.028	0.030	0.031
A1	-	0.02	0.05	-	0.001	0.002
A3	0.18	0.20	0.25	0.007	0.008	0.010
b	0.25	0.30	0.35	0.010	0.012	0.014
D	1.95	2.00	2.05	0.077	0.079	0.081
D2	1.00	-	1.45	0.039	-	0.057
e	0.65 BSC			0.026 BSC		
E	1.95	2.00	2.05	0.077	0.079	0.081
E2	0.50	-	0.85	0.020	-	0.033
L	0.25	0.30	0.40	0.010	0.012	0.016
h	0.1	0.15	0.2	0.004	0.006	0.008

Package Dimension

SOT23-5L PLASTIC PACKAGE



Dimensions				
SYMBOL	Millimeters		Inches	
	MIN	MAX	MIN	MAX
A	0.95	1.45	0.037	0.057
A1	0.05	0.15	0.002	0.006
A2	0.90	1.30	0.035	0.051
b	0.30	0.50	0.012	0.020
c	0.08	0.20	0.003	0.008
D	2.80	3.00	0.110	0.118
E	2.60	3.00	0.102	0.118
E1	1.50	1.70	0.059	0.067
e	0.95 (TYP)		0.037 (TYP)	
e1	1.90 (TYP)		0.075 (TYP)	
L	0.35	0.55	0.014	0.022
L1	0.60 (TYP)		0.024 (TYP)	
G	0.25 (TYP)		0.010 (TYP)	
θ	0°	8°	0°	8°

NOTICE

Information furnished is believed to be accurate and reliable. However Globaltech Semiconductor assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties, which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Globaltech Semiconductor. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information without express written approval of Globaltech Semiconductor.

CONTACT US

GS Headquarter	
	4F.,No.43-1,Lane11,Sec.6,Minquan E.Rd Neihu District Taipei City 114, Taiwan (R.O.C)
	886-2-2657-9980
	886-2-2657-3630
@	sales_twn@gs-power.com

RD Division	
	824 Bolton Drive Milpitas. CA. 95035
	1-408-457-0587